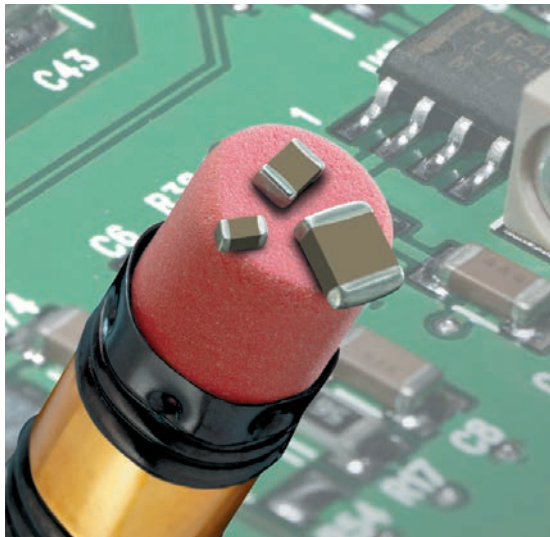




TANCERAM® chip capacitors can replace tantalum capacitors in many applications and offer several key advantages over traditional tantalums. Because TANCERAM® capacitors exhibit extremely low ESR, equivalent circuit performance can often be achieved using considerably lower capacitance values. Low DC leakage reduces current drain, extending the battery life of portable products. TANCERAM® high DC breakdown voltage ratings offer improved reliability and eliminate large voltage de-rating common when designing with tantalums.

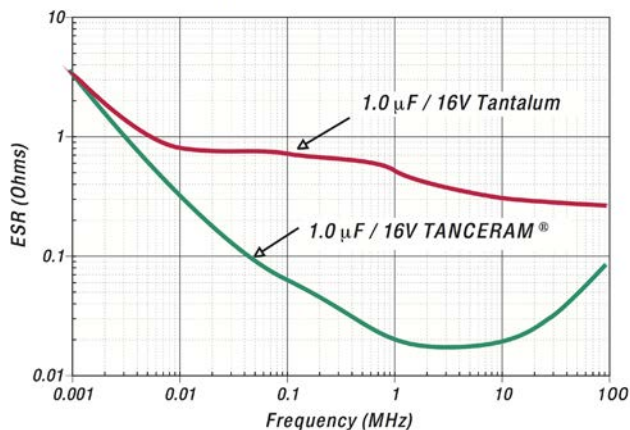
ADVANTAGES

- Low ESR
- Low DC Leakage
- Higher Surge Voltage
- Non-polarized Devices
- Reduced CHIP Size
- Improved Reliability
- Higher Insulation Resistance
- Higher Ripple Current

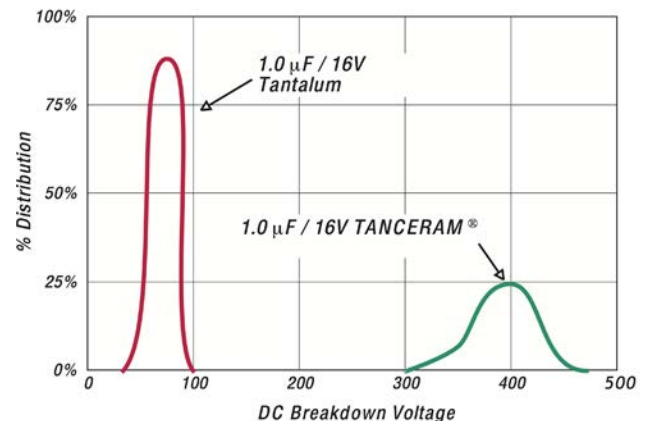
APPLICATIONS

- Switching Power Supply Smoothing (Input/Output)
- Backlighting Inverters
- DC/DC Converter Smoothing (Input/Output)
- General Digital Circuits

Typical ESR Comparison



Typical Breakdown Voltage Comparison



HOW TO ORDER TANCERAM®

Part number written: 100R15X106MV4E

100	R15	X	106	M	V	4	E
VOLTAGE	SIZE	DIELECTRIC	CAPACITANCE	TOLERANCE	TERMINATION	MARKING	PACKING
6R3 = 6.3 V 100 = 10 V 160 = 16 V 250 = 25 V 500 = 50 V 101 = 100 V	See Chart	W = X7R X = X5R	1st two digits are significant; third digit denotes number of zeros. 105 = 1.00 μF 476 = 47.0 μF 107 = 100 μF	K = ±10% M = ±20%	V = Nickel Barrier with 100% Tin Plating (Matte) T = SnPb* (*available on select parts)	4 = Unmarked	Code Type Reel E Plastic 7" T Paper 7" Tape specifications conform to EIA RS481

CAPACITANCE SELECTION

[illegible]

ELECTRICAL CHARACTERISTICS

DIELECTRIC:	X7R	X5R
TEMPERATURE COEFFICIENT:	±15% (-55 to +125°C)	±15% (-55 to +85°C)
DISSIPATION FACTOR:	For ≥ 50 VDC: 5% max. For ≤ 35 VDC: 10% max.	For ≥ 50 VDC: 5% max. For ≤ 35 VDC: 10% max.
INSULATION RESISTANCE (MIN. @ 25°C, WVDC)	100 ΩF or 10 GΩ, whichever is less	
DIELECTRIC STRENGTH:	2.5 X WVDC, 25°C, 50mA max.	
TEST CONDITIONS:	Capacitance values ≤ 10 μF: 1.0kHz±50Hz @ 1.0±0.2 Vrms Capacitance values > 10 μF: 120Hz±10Hz @ 0.5V±0.1 Vrms	
OTHER:	See page 70 for additional dielectric specifications.	